

General Description

Applications

The MAX9164 high-speed LVDS driver/receiver is designed specifically for low-power point-to-point applications. The MAX9164 operates from a single 3.3V power supply, and is pin compatible with DS90LV019. The device features an independent differential driver and receiver.

The MAX9164 driver output uses a current-steering configuration to generate a 3.1mA drive current. The driver accepts a single-ended input and translates it to LVDS signals at speeds up to 200Mbps over controlled-impedance media of approximately 100Ω . The transmission media may be printed circuit board traces or cables. The enable logic input, DE, is used to enable or disable the driver.

The MAX9164 receiver detects a differential input as low as 100mV and translates it to single-ended output at speeds up to 200Mbps. The enable logic input, RE, is used to enable or disable the receiver.

Inputs and outputs conform to the ANSI TIA/EIA-644 LVDS standard. The MAX9164 is offered in 14-lead SO and TSSOP packages, and is specified for operation from -40°C to +85°C.

Cell-Phone Base Stations	Network Switches/Routers
Add/Drop Muxes	Backplane Interconnect
Digital Cross-Connects	Clock Distribution
DSLAMs	

_____Features

- ♦ 3.3V Operation
- ♦ 35% Lower Power than DS90LV019
- ♦ 200Mbps Data Signaling Rate
- ♦ ±1V Common-Mode Range
- ♦ ±100mV Receiver Sensitivity
- Flow-Through Pinout
- Receiver Output High for Open Input

_Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX9164ESD	-40°C to +85°C	14 SO
MAX9164EUD	-40°C to +85°C	14 TSSOP

Pin Configuration



Typical Application Circuit



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For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

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ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND0.3V to +4.0V	Operating Temperature Range40°C to +85°C
DO+, DO-, RI+, RI- to GND0.3V to +4.0V	Junction Temperature+150°C
DIN, ROUT, DE, RE to GND0.3V to (V _{CC} + 0.3V)	Storage Temperature Range65°C to +150°C
Driver Short-Circuit CurrentContinuous	ESD Protection
Continuous Power Dissipation ($T_A = +70^{\circ}C$)	HBM (1.5k Ω , 100pF), DO+, DO-, RI+, RI-, DE, \overline{RE} , DIN,
14-Pin SO (derate 8.3mW/°C above +70°C)667mW	ROUT> ±2kV
14-Pin TSSOP (derate 9.1mW/°C above +70°C)727mW	Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = 3.0V \text{ to } 3.6V, |V_{ID}| = 0.1V \text{ to } 2.4V, \text{ common-mode input voltage } (V_{CM}) = |V_{ID}/2| \text{ to } 2.4V - |V_{ID}|/2, R_L = 100\Omega \pm 1\%, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$. Typical values are at $V_{CC} = 3.3V, |V_{ID}| = 0.2V, V_{CM} = 1.2V, T_A = +25^{\circ}\text{C}$, unless otherwise noted.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS
SINGLE-ENDED INPUTS (DIN, DE, RE)						
Input High Voltage	VIH		2.0		Vcc	V
Input Low Voltage	VIL		0		0.8	V
Input Current	lin	$\overline{\text{RE}}$, DE, DIN = high or low	-10		+10	μA
Input Diode Clamp Voltage	VCL	I _{CLAMP} = -18mA	-1.5			V
DRIVER OUTPUT (DO+, DO-)	-					-
Differential Output Voltage	VOD	Figure 1	250	310	450	mV
Change in Magnitude of V _{OD} Between Complementary Output States	ΔV_{OD}	Figure 1		0.02	25	mV
Offset Voltage	Vos	Figure 1	1.0	1.29	1.7	V
Change in Magnitude of V _{OS} Between Complementary Output States	ΔV_{OS}	Figure 1		0.8	25	mV
High-Impedance Leakage Current	IOZD	$DE = 0; DO+, DO- = V_{CC} \text{ or } 0$	-1		+1	μA
Power-Off Leakage Current	IOXD	DO+, DO- = $3.6V$ or 0; $V_{CC} = 0$	-1		+1	μA
	I _{OSD}	$DO+ = 0$ at $DIN = V_{CC}$		-3	-10	m۸
Output Short-Circuit Current		DO- = 0 at DIN = 0		-3	-10	ША
Output Capacitance	C _{DO}	Capacitance from DO+ or DO- to 0		3.7		pF
RECEIVER INPUT (RI+, RI-)						
Differential Input High Threshold	VTH				100	mV
Differential Input Low Threshold	V _{TL}		-100			mV
Input Current	I _{IN}	V _{CC} = 3.6V or 0; RI+, RI- = 2.4V or 0	-10		+10	μA
Input Capacitance	C _{RI}	RI+ or RI- to 0		5		рF
RECEIVER OUTPUT (ROUT)						
Output High Voltage	VOH	$I_{OH} = -400\mu A$ $V_{ID} = 100mV$ RI+, RI- open	2.9	3.28		V
Output Low Voltage	V _{OL}	$I_{OL} = +2.0 \text{mA}, V_{ID} = -100 \text{mV}$		0.025	0.4	V
Output Short-Circuit Current	los	$V_{ID} = +100 \text{mV}, \text{ROUT} = 0$	-20	-28	-75	mA



DC ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = 3.0V \text{ to } 3.6V, |V_{ID}| = 0.1V \text{ to } 2.4V, \text{ common-mode input voltage } (V_{CM}) = |V_{ID}/2| \text{ to } 2.4V - |V_{ID}|/2, R_L = 100\Omega \pm 1\%, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$. Typical values are at $V_{CC} = 3.3V, |V_{ID}| = 0.2V, V_{CM} = 1.2V, T_A = +25^{\circ}\text{C}$, unless otherwise noted.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
SUPPLY CURRENT						
Supply Current	Icc	$DE = V_{CC}, \overline{RE} = 0$		7.4	12.5	mA
Driver Supply Current	ICCD	$DE = \overline{RE} = V_{CC}$		7.4	12.5	mA
Receiver Supply Current	ICCR	$DE = \overline{RE} = 0$		4.4	7.0	mA
Disable Supply Current	ICCZ	$DE = 0, \overline{RE} = V_{CC}$		4.4	7.0	mA

AC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = 3.0V \text{ to } 3.6V, |V_{ID}| = 0.2V, V_{CM} = 1.2V, R_L = 100\Omega \pm 1\%, C_L = 10pF, T_A = -40^{\circ}C \text{ to } +85^{\circ}C.$ Typical values are at $V_{CC} = 3.3V, |V_{ID}| = 0.2V, V_{CM} = 1.2V, T_A = +25^{\circ}C, unless otherwise noted.) (Notes 3, 4, 5)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS	
DRIVER							
Differential High-to-Low Propagation Delay	t PHLD	Figure 2	2.0	4.4	6.5	ns	
Differential Low-to-High Propagation Delay	t PLHD	Figure 2	1.0	4.2	7.0	ns	
Differential Skew tPHLD - tPLHD	t SKD	Figure 2		0.2	1.0	ns	
Rise Time	t tlhd	Figure 2	0.2	0.9	3.0	ns	
Fall Time	t THLD	Figure 2	0.2	0.8	3.0	ns	
Disable Time High to Z	t _{PHZ}	Figure 3	1.5	6.0	8.0	ns	
Disable Time Low to Z	t PLZ	Figure 3	2.5	5.5	9.0	ns	
Enable Time Z to High	t _{PZH}	Figure 3	4.0	5.5	8.0	ns	
Enable Time Z to Low	t _{PZL}	Figure 3	3.8	5.0	8.0	ns	
RECEIVER	RECEIVER						
Differential High-to-Low Propagation Delay	t PHL	Figure 4	3.0	5.4	7.0	ns	
Differential Low-to-High Propagation Delay	t PLH	Figure 4	3.0	5.3	9.0	ns	
Differential Skew tPHL - tPLH	T _{SK}	Figure 4		0.14	1.5	ns	
Rise Time	tтLн	Figure 4	0.15	0.8	3.0	ns	
Fall Time	t _{THL}	Figure 4	0.15	0.4	3.0	ns	
Disable Time High to Z	t _{PHZ}	Figure 5	3.0	5.4	6.0	ns	
Disable Time Low to Z	t PLZ	Figure 5	3.0	5.1	6.0	ns	
Enable Time Z to High	t PZH	Figure 5	3.0	5.4	8.0	ns	
Enable Time Z to Low tPZL		Figure 5	3.0	5.1	8.0	ns	

Note 1: Maximum and minimum limits over temperature are guaranteed by design and characterization. Devices are 100% tested at $T_A = +25^{\circ}C$.

Note 2: Current into a pin is defined as positive. Current out of a pin is defined as negative. All voltages are referenced to device ground except V_{TH} , V_{ID} , V_{OD} , and ΔV_{OD} .

Note 3: C_L includes probe and jig capacitance.

Note 4: AC parameters are guaranteed by design and characterization.

Note 5: Generator waveforms for all tests unless otherwise specified: f = 100MHz, $Z_0 = 50\Omega$, $t_R = t_F = 6.0$ ns (0 to 3V, 0% to 100%) for DE and \overline{RE} , $t_R = t_F = 3.0$ ns (0 to 3V, 0% to 100%) for DIN, and $t_R = t_F = 1.0$ ns (IV_{ID}I = 0.2V, 20% to 80%) for RI+/RI-inputs.



Typical Operating Characteristics

 $(V_{CC} = 3.3V, |V_{ID}| = 0.2V, V_{CM} = 1.2V, R_L = 100\Omega \pm 1\%$, FREQ = 100MHz, $C_L = 10$ pF, $T_A = +25$ °C, unless otherwise noted.)



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Typical Operating Characteristics (continued)

 $(V_{CC} = 3.3V, |V_{ID}| = 0.2V, V_{CM} = 1.2V, R_L = 100\Omega \pm 1\%$, FREQ = 100MHz, $C_L = 10$ pF, $T_A = +25^{\circ}C$, unless otherwise noted.)



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Pin Description

PIN	NAME	FUNCTION			
1	DE	LVTTL/LVCMOS Driver Enable Input. The driver is enabled when DE is high. When DE is low, the driver outputs, DO+ and DO-, are disabled and are high impedance.			
2	DIN	LVTTL/LVCMOS Driver Input			
3, 5, 6, 13	N.C.	No Connection. Not internally connected.			
4	ROUT	LVTTL/LVCMOS Receiver Output			
7	GND	Ground			
8	RE	LVTTL/LVCMOS Receiver Enable Input. The receiver is enabled when $\overline{\text{RE}}$ is low. When $\overline{\text{RE}}$ is high, the receiver output is disabled and is high impedance.			
9	RI-	Inverting LVDS Receiver Input. RI- has an integrated pulldown to GND.			
10	RI+	Noninverting LVDS Receiver Input. RI+ has an integrated pullup to V _{CC} .			
11	DO-	Inverting LVDS Driver Output			
12	DO+	Noninverting LVDS Driver Output			
14	V _{CC}	Power-Supply Input. Bypass V_{CC} to GND with 0.1µF and 0.001µF ceramic capacitors.			



Figure 1. Differential Driver DC Test Circuit

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Figure 2. Driver Differential Propagation Delay and Transition Time Test Circuit and Waveforms



Figure 3. Driver High-Impedance Delay Test Circuit and Waveforms



Figure 4. Receiver Propagation Delay and Transition Time Test Circuit and Waveforms



Figure 5. Receiver High-Impedance Delay Test Circuit and Waveforms

Detailed Description

The MAX9164 high-speed LVDS driver/receiver is designed specifically for low-power point-to-point applications. The MAX9164 operates from a single 3.3V power supply, and is pin compatible with the DS90LV019. The device features an independent differential driver and receiver.

The MAX9164 driver outputs use a current-steering configuration to generate a 3.1mA (typ) output current. This current-steering approach induces less ground bounce and no shoot-through current, enhancing noise margin and system speed performance. The outputs are short-circuit current limited. The MAX9164 output requires a resistive load to terminate the signal and complete the transmission loop. With a typical 3.1mA output current, the MAX9164 produces a 310mV output voltage when driving a bus terminated with a 100 Ω resistor (3.1mA x 100 Ω = 310mV).

The MAX9164 receiver detects a differential input as low as 100mV and translates it to single-ended output. The device features input biasing that drives the output high if the inputs are left open.

Power-On Reset

The power-on reset voltage of the MAX9164 is typically 2.2V. When the supply falls below this voltage, the device is disabled and the outputs (DO+, DO-, and ROUT) are high impedance.

Applications Information

Power-Supply Bypassing

Bypass V_{CC} with high-frequency, surface-mount ceramic 0.1μ F and 0.001μ F capacitors in parallel as close to the device as possible, with the smaller valued capacitor closest to V_{CC}.

Termination The MAX9164 requires an external termination resistor at the differential input. This termination resistor should match the differential impedance of the input transmission line. The differential output requires a termination resistor at the far end of the transmission line. This termination resistor should match the differential impedance of the output transmission line.

These termination resistors are typically 100Ω . Minimize the distance between the input termination resistor and the MAX9164 receiver input.

Traces, Cables, and Connectors

The characteristics of differential input and output connections affect the performance of the device. Use controlled-impedance traces, cables, and connectors with matched characteristic impedance.

Ensure that noise couples as common mode by running the traces of a differential pair close together. Reduce within-pair skew by matching the electrical length of the conductors within a differential pair. Excessive skew can result in a degradation of magnetic field cancellation.

Maintain the distance between conductors within a differential pair to avoid discontinuities in differential impedance. Minimize the number of vias to further prevent impedance discontinuities.

Board Layout

For LVDS applications, a four-layer PC board with separate power, ground, LVDS, and logic signal layers is recommended. Separate the LVTTL/LVCMOS and LVDS signals to prevent coupling.

Chip Information

TRANSISTOR COUNT: 901 PROCESS: CMOS

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to **www.maxim-ic.com/packages**.)



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Package Information (continued)

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